SiC Schottky Barrier Diode

Datasheet

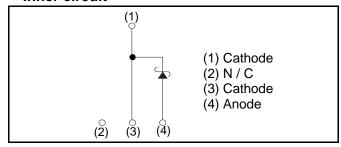
V_R	650V
I _F	10A
Q_C	15nC

●Outline LPT(L) <TO-263AB> (2) (3) (4)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

•Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

_	- 	1
F	Packaging	Embossed tape
	Reel size (mm)	330
Type	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS210AJ

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward	d current (T _c = 137°C)	I _F	10	А
PW=10ms sinusoidal, T _j =25°C			38	А
Surge non- repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	30	А
	PW=10μs square, T _j =25°C		150	А
Repetitive peak forward current		I _{FRM}	45 *1	А
$i^{2}t \text{ value}$ $PW=10\text{ms, T}_{j}=25^{\circ}\text{C}$ $PW=10\text{ms, T}_{j}=150^{\circ}\text{C}$		ſ.2	7.2	A ² s
		$\int i^2 dt$	4.5	A ² s
Total power dissipation		P_{D}	83 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =2.0mA	650	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =10A,T _j =150°C	-	1.55	-	V
		I _F =10A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,T _j =25°C	-	2	200	μΑ
		V _R =600V,T _j =150°C	-	30	-	μΑ
		V _R =600V,T _j =175°C	-	70	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	360	-	pF
		V _R =600V,f=1MHz	-	37	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	15	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns

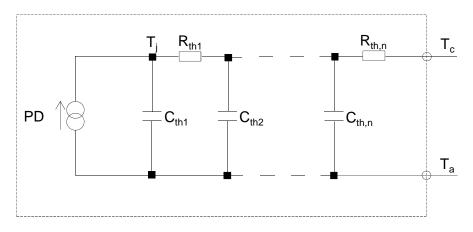
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.5	1.8	°C/W

●Typical Transient Thermal Characteristics

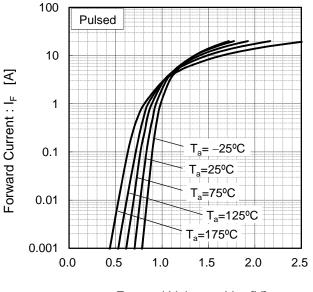
Symbol	Value	Unit
R _{th1}	5.01E-02	
R _{th2}	1.14E+00	K/W
R _{th3}	3.10E-01	

Symbol	Value	Unit
C_{th1}	1.43E-03	
C_{th2}	8.50E-04	Ws/K
C_{th3}	1.14E-01	



Electrical characteristic curves

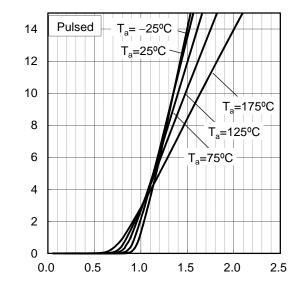
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

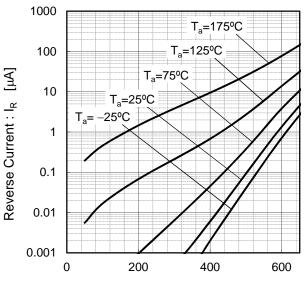
Fig.2 V_F - I_F Characteristics

Forward Current : I_F [A]



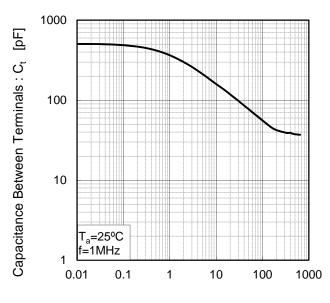
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

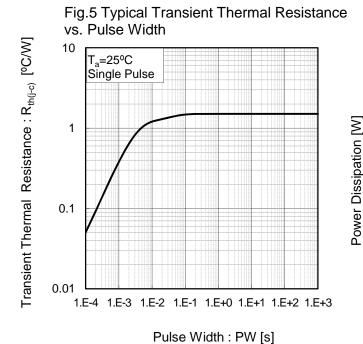


Fig.6 Power Dissipation

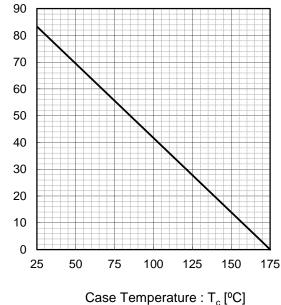
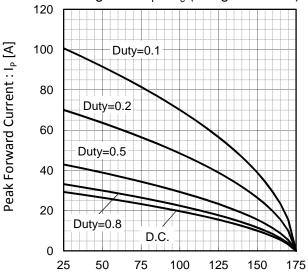


Fig.7*3 Maximum peak forward current derating curve I_P - T_c 120 100 Peak Forward Current : Ip [A] 80 Duty=0.1 60 Duty=0.2 40 Duty=0.5 20 Duty=0.8 D.C. 0 50 75 100 125 25 150 175

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



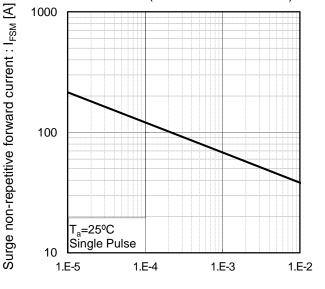
Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C] *4 Based on typ Vf, typ $R_{th(j-c)}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Forward Current: IF

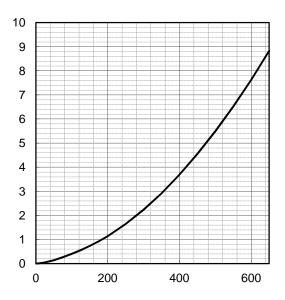
Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

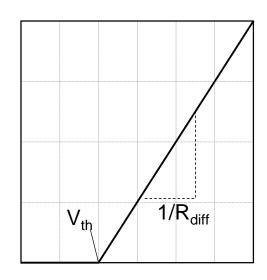


Capacitance stored energy : $E_C[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	3.98E-02	Ω
b ₁	1.02E-04	Ω/°C
b ₂	1.08E-06	$\Omega/^{\circ}C^{2}$

 T_i in ${}^{\circ}C$; -55 ${}^{\circ}C$ < T_i < ${}^{\circ}C$; I_F < 20 A

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